1MHz, 20µA, Rail-to-Rail I/O Op Amps with Shutdown

General Description

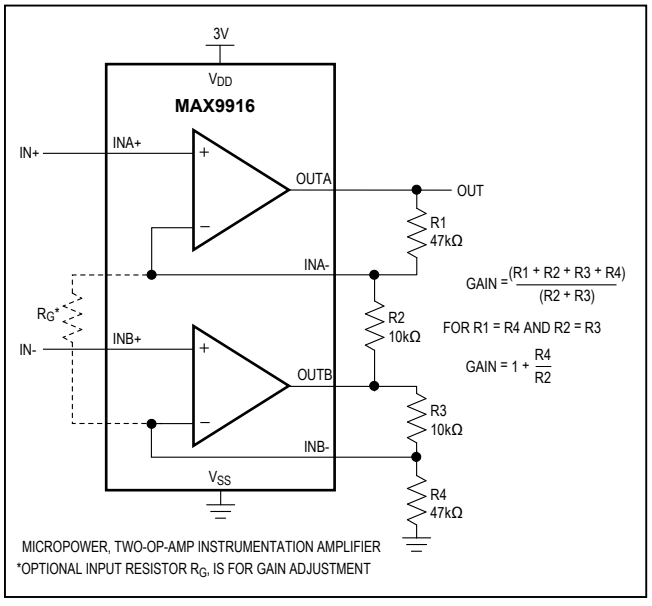
The single MAX9914/MAX9915 and dual MAX9916/MAX9917 operational amplifiers feature maximized ratio of gain bandwidth to supply current and are ideal for battery-powered applications such as portable instrumentation, portable medical equipment, and wireless handsets. These CMOS op amps feature an ultra-low 1pA input bias current, rail-to-rail inputs and outputs, low 20µA supply current, and operate from a single 1.8V to 5.5V supply. For additional power conservation, the MAX9915/MAX9917 feature a low-power shutdown mode that reduces supply current to 1nA, and puts the amplifier outputs in a high-impedance state. These devices are unity-gain stable with a 1MHz gain-bandwidth product.

The MAX9914 and MAX9915 are available in 5-pin and 6-pin SC70 packages, respectively. The MAX9916 is available in an 8-pin SOT23 package, and the MAX9917 in a 10-pin µMAX® package. All devices are specified over the -40°C to +85°C extended operating temperature range.

Applications

- Portable Medical Devices
- Portable Test Equipment
- RF Tags
- Laptops
- Data-Acquisition Equipment

Typical Operating Circuit



MICROPOWER, TWO-OP-AMP INSTRUMENTATION AMPLIFIER
*OPTIONAL INPUT RESISTOR R_G, IS FOR GAIN ADJUSTMENT

Features

- High 1MHz GBW
- Ultra-Low 20µA Supply Current
- Single 1.8V to 5.5V Supply Voltage Range
- Ultra-Low 1pA Input Bias Current
- Rail-to-Rail Input and Output Voltage Ranges
- Low ±200µV Input Offset Voltage
- Low 0.001µA Shutdown Current
- High-Impedance Output During Shutdown (MAX9915/MAX9917)
- Unity-Gain Stable
- Available in Tiny SC70, SOT23, and µMAX Packages

Ordering Information

PART	TEMP RANGE	PIN-PACKAGE	TOP MARK
MAX9914EXK+T	-40°C to +85°C	5 SC70	AGB
MAX9914EXK-T	-40°C to +85°C	5 SC70	AGB
MAX9915EXT+T	-40°C to +85°C	6 SC70	ACB
MAX9915EXT-T	-40°C to +85°C	6 SC70	ACB
MAX9916EKA+T	-40°C to +85°C	8 SOT23	AEJZ
MAX9916EKA-T	-40°C to +85°C	8 SOT23	AEJZ
MAX9917EUB	-40°C to +85°C	10 µMAX	—
MAX9917EUB+	-40°C to +85°C	10 µMAX	—

+Denotes a lead(Pb)-free/RoHS-compliant package.
T = Tape and reel.

Selector Guide

PART	AMPLIFIERS PER PACKAGE	SHUTDOWN MODE	PACKAGE
MAX9914EXK+T	1	No	5 SC70
MAX9915EXT+T	1	Yes	6 SC70
MAX9916EKA+T	2	No	8 SOT23
MAX9917EUB+	2	Yes	10 µMAX

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Absolute Maximum Ratings

Power-Supply Voltage (V_{DD} to V_{SS}).....-0.3V to +6.0V
IN_+, IN_-, OUT_, $\overline{SHDN\_}$.....(V_{SS} - 0.3V) to (V_{DD} + 0.3V)
Current into IN_+, IN_-.....±20mA
Output Short-Circuit Duration to V_{DD} or V_{SS}.....Continuous
Continuous Power Dissipation (T_A = +70°C)
5-Pin SC70 (derate 3.1mW/°C above +70°C).....247mW
6-Pin SC70 (derate 3.1mW/°C above +70°C).....245mW
8-Pin SOT23 (derate 5.1mW/°C above +70°C).....408mW
10-Pin µMAX (derate 5.6mW/°C above +70°C).....444mW
Operating Temperature Range..... -40°C to +85°C
Junction Temperature.....+150°C
Storage Temperature Range..... -65°C to +150°C
Lead Temperature (soldering, 10s).....+300°C
Soldering Temperature (reflow).....+260°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Electrical Characteristics

(V_{DD} = 1.8V to 5.5V, V_{SS} = 0V, V_{CM} = 0V, V_{OUT} = V_{DD}/2, R_L = ∞ connected to V_{DD}/2, $\overline{SHDN\_}$ = V_{DD}, **T_A = +25°C**, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Supply Voltage Range	V_{DD}	Guaranteed by PSRR test		1.8		5.5	V
Supply Current	I_{DD}	MAX9914/MAX9915	V_{DD} = 1.8V		20		µA
			V_{DD} = 5.5V		20	25	
		MAX9916/MAX9917	V_{DD} = 1.8V		40		
			V_{DD} = 5.5V		40	50	
Shutdown Supply Current	$I_{DD(\overline{SHDN\_})}$	$\overline{SHDN\_}$ = GND, MAX9915/MAX9917			0.001	0.5	µA
Input Offset Voltage	V_{OS}				±0.2	±1	mV
Input-Offset-Voltage Matching		MAX9916/MAX9917			±250		µV
Input Bias Current	I_B	(Note 2)			±1	±10	pA
Input Offset Current	I_{OS}	(Note 2)			±1	±10	pA
Input Resistance	R_{IN}	Common mode			1		GΩ
		Differential mode, -1mV < V_{IN} < +1mV			10		
Input Common-Mode Range	V_{CM}	Guaranteed by CMRR test		V_{SS} - 0.1		V_{DD} + 0.1	V
Common-Mode Rejection Ratio	CMRR	-0.1V < V_{CM} < V_{DD} + 0.1V, V_{DD} = 5.5V		70	80		dB
Power-Supply Rejection Ratio	PSRR	1.8V < V_{DD} < 5.5V		65	85		dB
Open-Loop Gain	A_{VOL}	25mV < V_{OUT} < V_{DD} - 25mV, R_L = 100kΩ, V_{DD} = 5.5V		95	120		dB
		100mV < V_{OUT} < V_{DD} - 100mV, RL = 5kΩ, V_{DD} = 5.5V		95	110		
Output-Voltage-Swing High	V_{OH}	V_{DD} - V_{OUT}	R_L = 100kΩ		2.5	5	mV
			R_L = 5kΩ		50	70	
			R_L = 1kΩ		250		
Output-Voltage-Swing Low	V_{OL}	V_{OUT} - V_{SS}	R_L = 100kΩ		2.5	5	mV
			R_L = 5kΩ		50	70	
			R_L = 1kΩ		250		
Channel-to-Channel Isolation	CH_{ISO}	Specified at DC, MAX9916/MAX9917			100		dB
Output Short-Circuit Current	$I_{OUT(SC)}$				±15		mA

Electrical Characteristics (continued)

(V_{DD} = 1.8V to 5.5V, V_{SS} = 0V, V_{CM} = 0V, V_{OUT} = V_{DD}/2, R_L = ∞ connected to V_{DD}/2, $\overline{SHDN}\_$ = V_{DD}, **T_A = +25°C**, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
$\overline{SHDN}\_$ Logic Low	V_{IL}	V_{DD} = 1.8V to 3.6V, MAX9915/MAX9917				0.4	V
		V_{DD} = 3.6V to 5.5V, MAX9915/MAX9917				0.8	
$\overline{SHDN}\_$ Logic High	V_{IH}	V_{DD} = 1.8V to 3.6V, MAX9915/MAX9917		1.4			V
		V_{DD} = 3.6V to 5.5V, MAX9915/MAX9917		2			
$\overline{SHDN}\_$ Input Bias Current	I_{IL}	$\overline{SHDN}\_$ = V_{SS}, MAX9915/MAX9917 (Note 2)				1	nA
	I_{IH}	$\overline{SHDN}\_$ = V_{DD}, MAX9915/MAX9917				500	
Output Leakage in Shutdown	$I_{OUT(\overline{SHDN}\_)}$	$\overline{SHDN}\_$ = V_{SS}, V_{OUT} = 0V to V_{DD}, MAX9915/MAX9917			1	500	nA
Gain-Bandwidth Product					1		MHz
Phase Margin		C_L = 15pF			45		degrees
Gain Margin		C_L = 15pF			10		dB
Slew Rate					0.5		V/µs
Capacitive-Load Stability (See the *Driving Capacitive Loads* Section)	C_{LOAD}	No sustained oscillations	A_V = 1V/V		30		pF
			A_V = 10V/V		100		
			R_L = 5kΩ, A_V = 1V/V		100		
			R_{ISO} = 1kΩ, A_V = 1V/V		100		
Input Voltage-Noise Density		f = 1kHz			160		nV/√Hz
Input Current-Noise Density		f = 1kHz			0.001		pA/√Hz
Settling Time		To 0.1%, V_{OUT} = 2V step, A_V = -1V/V			3.5		µs
Delay Time to Shutdown	t_{SH}	I_{DD} = 5% of normal operation, V_{DD} = 5.5V, $V_{\overline{SHDN}\_}$ = 5.5V to 0 step			2		µs
Delay Time to Enable	t_{EN}	V_{OUT} = 2.7V, V_{OUT} settles to 0.1%, V_{DD} = 5.5V, $V_{\overline{SHDN}\_}$ = 0 to 5.5V step			10		µs
Power-Up Time		V_{DD} = 0 to 5.5V step			2		µs

Electrical Characteristics

(V_{DD} = 1.8V to 5.5V, V_{SS} = 0V, V_{CM} = 0V, V_{OUT} = V_{DD}/2, R_L = ∞ connected to V_{DD}/2, $\overline{SHDN}\_$ = V_{DD}, **T_A = -40°C to +85°C**, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Supply Voltage Range	V_{DD}	Guaranteed by PSRR test		1.8		5.5	V
Supply Current	I_{DD}	MAX9914/MAX9915	V_{DD} = 5.5V			29	µA
		MAX9916/MAX9917				60	
Shutdown Supply Current	$I_{DD(\overline{SHDN}\_)}$	$\overline{SHDN}\_$ = GND, MAX9915/MAX9917				1	µA
Input Offset Voltage	V_{OS}					±3	mV

Electrical Characteristics (continued)

(V_{DD} = 1.8V to 5.5V, V_{SS} = 0V, V_{CM} = 0V, V_{OUT} = V_{DD}/2, R_L = ∞ connected to V_{DD}/2, $\overline{SHDN}\_$ = V_{DD}, **T_A = -40°C to +85°C**, unless otherwise noted.) (Note 1)

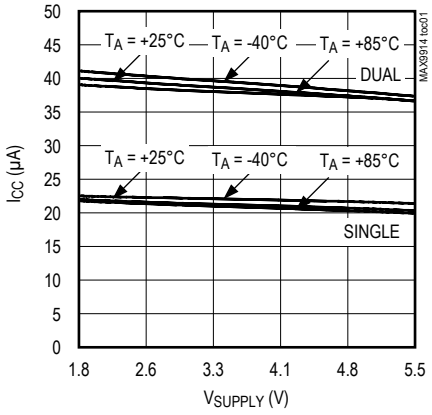
PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Input-Offset-Voltage Temperature Coefficient (Note 2)	TC_{VOS}				±5		µV/°C
Input Bias Current	I_B					±30	pA
Input Offset Current	I_{OS}					±20	pA
Input Common-Mode Range	V_{CM}	Guaranteed by CMRR test		V_{SS} - 0.05		V_{DD} + 0.05	V
Common-Mode Rejection Ratio	CMRR	-0.05V < V_{CM} < V_{DD} + 0.05V, V_{DD} = 5.5V		60			dB
Power-Supply Rejection Ratio	PSRR	1.8V < V_{DD} < 5.5V		60			dB
Open-Loop Gain	A_{VOL}	25mV < V_{OUT} < V_{DD} - 25mV, R_L = 100kΩ, V_{DD} = 5.5V		85			dB
		150mV < V_{OUT} < V_{DD} - 150mV, R_L = 5kΩ, V_{DD} = 5.5V		85			
Output-Voltage-Swing High	V_{OH}	V_{DD} - V_{OUT}	R_L = 100kΩ			6	mV
			R_L = 5kΩ			90	
Output-Voltage-Swing Low	V_{OL}	V_{OUT} - V_{SS}	R_L = 100kΩ			5	mV
			R_L = 5kΩ			90	
$\overline{SHDN}\_$ Logic Low	V_{IL}	V_{DD} = 1.8V to 3.6V, MAX9915/MAX9917				0.4	V
		V_{DD} = 3.6V to 5.5V, MAX9915/MAX9917				0.8	
$\overline{SHDN}\_$ Logic High	V_{IH}	V_{DD} = 1.8V to 3.6V, MAX9915/MAX9917		1.4			V
		V_{DD} = 3.6V to 5.5V, MAX9915/MAX9917		2			
$\overline{SHDN}\_$ Input Bias Current	I_{IL}	$\overline{SHDN}\_$ = V_{SS}, MAX9915/MAX9917				5	nA
	I_{IH}	$\overline{SHDN}\_$ = V_{DD}, MAX9915/MAX9917				1000	nA
Output Leakage in Shutdown	$I_{OUT(\overline{SHDN}\_)}$	$\overline{SHDN}\_$ = V_{SS}, V_{OUT} = 0V to V_{DD}, MAX9915/MAX9917				1000	nA

Note 1: Specifications are 100% tested at T_A = +25°C (exceptions noted). All temperature limits are guaranteed by design.
Note 2: Guaranteed by design, not production tested

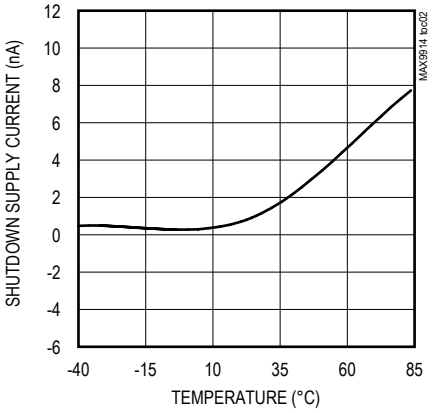
Typical Operating Characteristics

(V_{DD} = 3V, V_{SS} = V_{CM} = 0V, R_L to V_{DD}/2, T_A = +25°C, unless otherwise noted.)

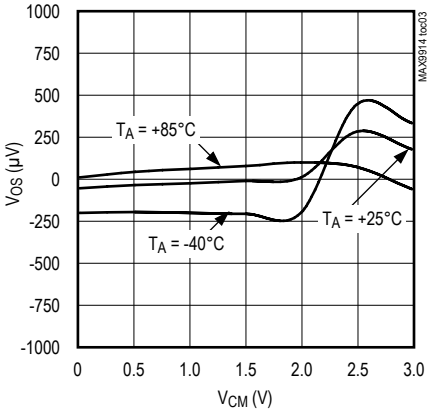
SUPPLY CURRENT vs. SUPPLY VOLTAGE



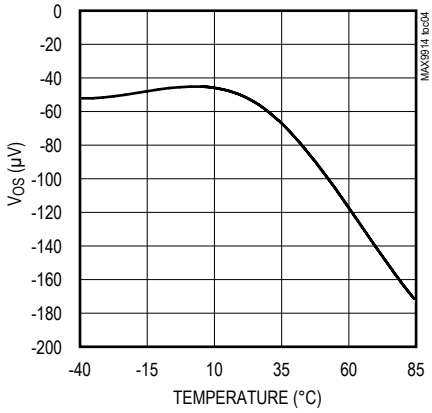
SHUTDOWN SUPPLY CURRENT vs. TEMPERATURE



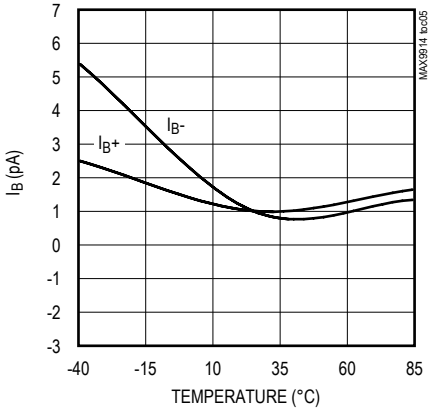
INPUT OFFSET VOLTAGE vs. INPUT COMMON-MODE VOLTAGE



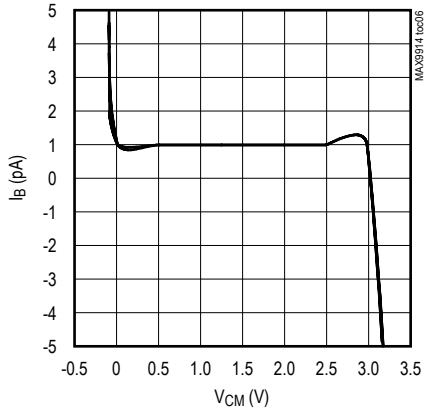
INPUT OFFSET VOLTAGE vs. TEMPERATURE



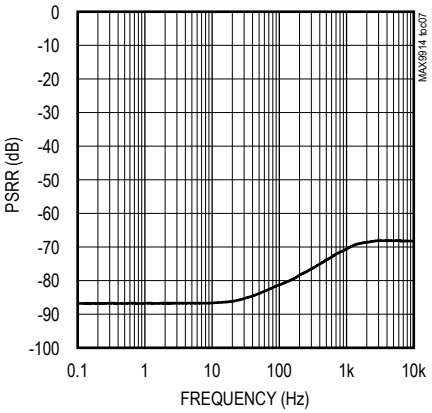
INPUT BIAS CURRENT vs. TEMPERATURE



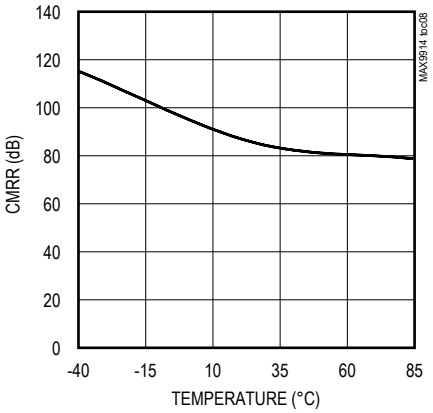
INPUT BIAS CURRENT vs. INPUT COMMON-MODE VOLTAGE



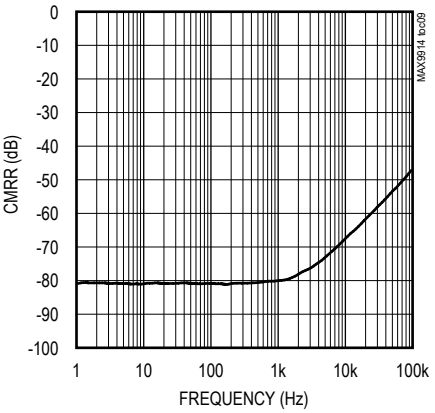
POWER-SUPPLY REJECTION RATIO vs. FREQUENCY



COMMON-MODE REJECTION RATIO vs. TEMPERATURE



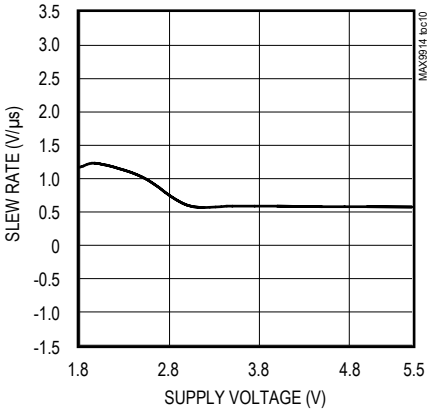
COMMON-MODE REJECTION RATIO vs. FREQUENCY



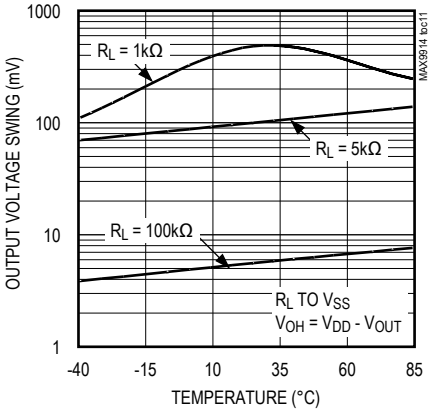
Typical Operating Characteristics (continued)

(V_{DD} = 3V, V_{SS} = V_{CM} = 0V, R_L to V_{DD}/2, T_A = +25°C, unless otherwise noted.)

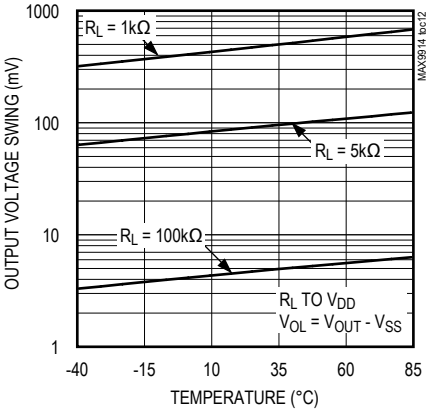
SLEW RATE vs. SUPPLY VOLTAGE



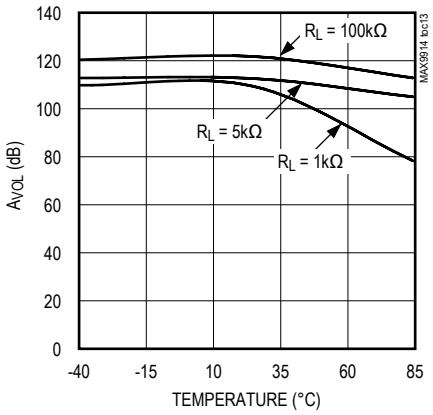
OUTPUT-SWING HIGH vs. TEMPERATURE



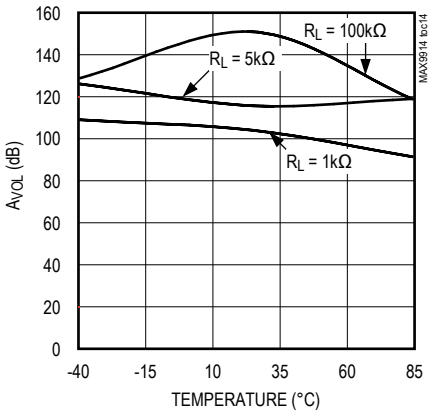
OUTPUT-SWING LOW vs. TEMPERATURE



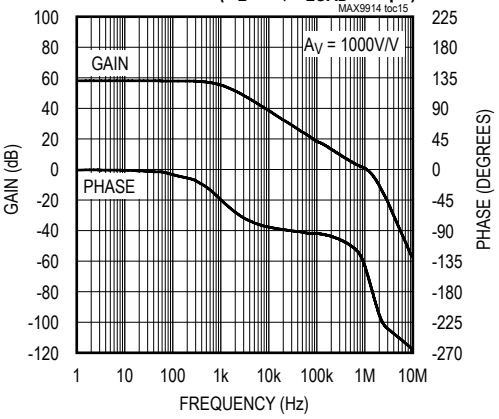
OPEN-LOOP GAIN vs. TEMPERATURE (R_L TO V_{SS})



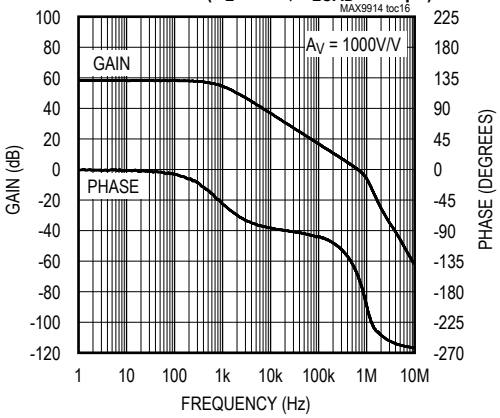
OPEN-LOOP GAIN vs. TEMPERATURE (R_L TO V_{DD})



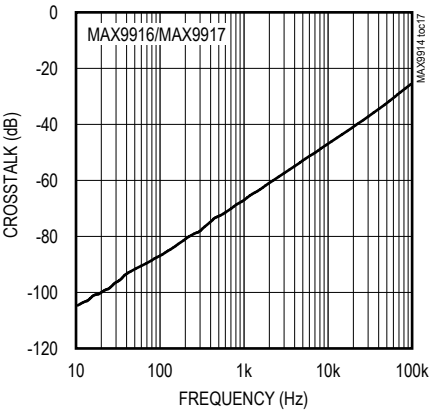
GAIN AND PHASE vs. FREQUENCY (R_L = ∞, C_{LOAD} = 15pF)



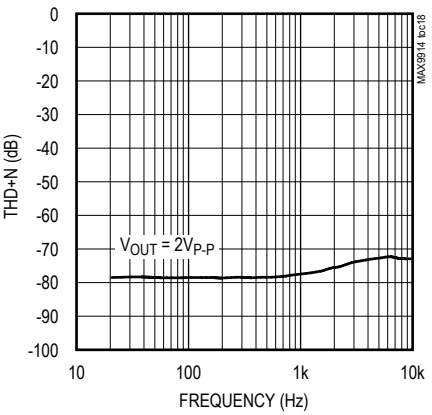
GAIN AND PHASE vs. FREQUENCY (R_L = 5kΩ, C_{LOAD} = 100pF)



CROSSTALK vs. FREQUENCY



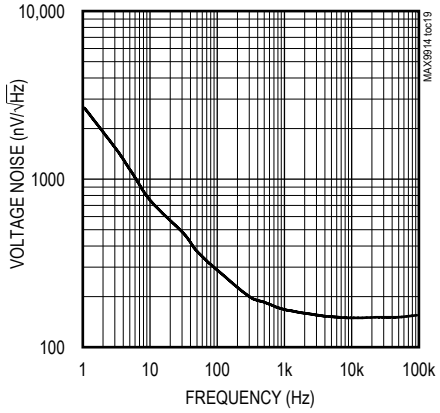
TOTAL HARMONIC DISTORTION PLUS NOISE vs. FREQUENCY



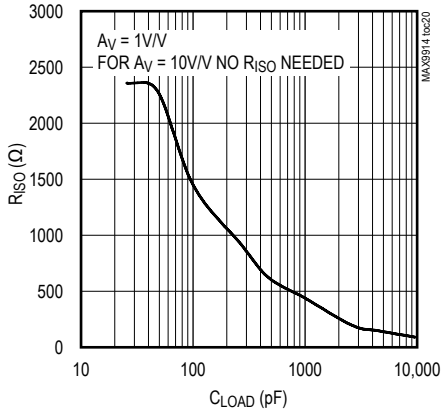
Typical Operating Characteristics (continued)

(V_{DD} = 3V, V_{SS} = V_{CM} = 0V, R_L to V_{DD}/2, T_A = +25°C, unless otherwise noted.)

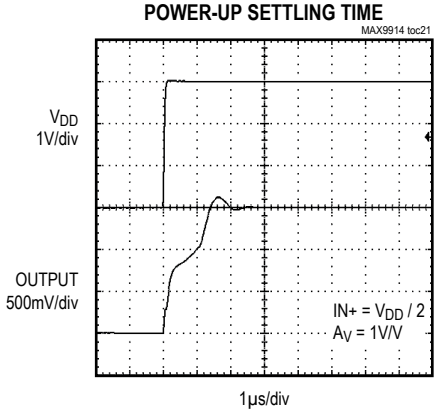
VOLTAGE-NOISE DENSITY vs. FREQUENCY



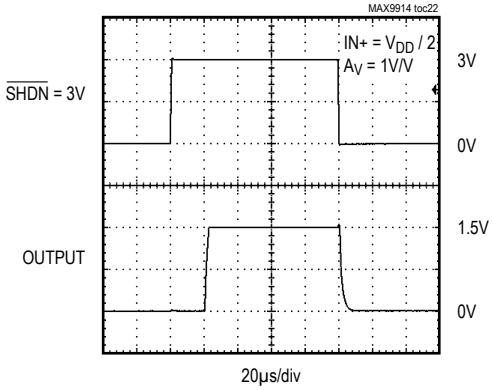
RESISTOR ISOLATION vs. CAPACITIVE LOAD



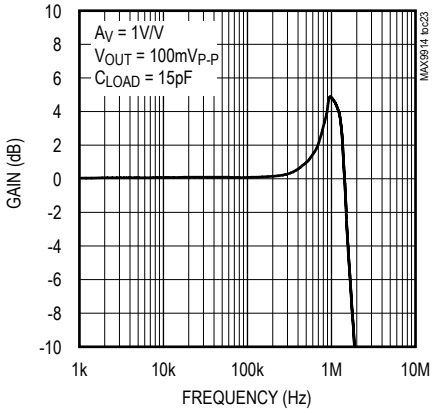
POWER-UP SETTLING TIME



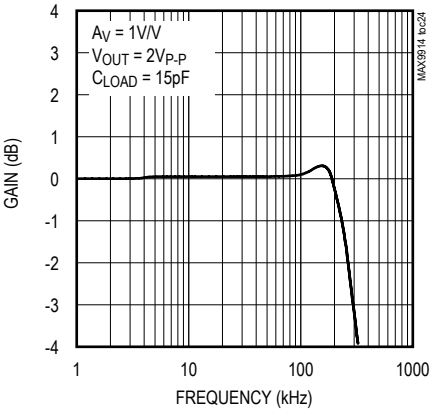
SHUTDOWN RESPONSE



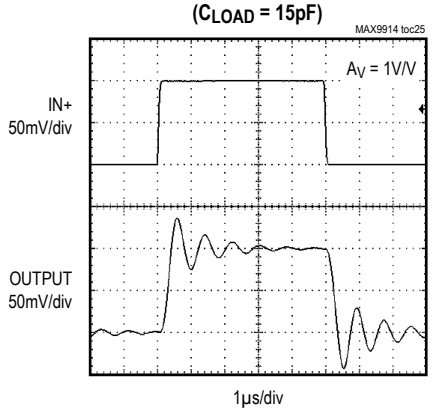
SMALL-SIGNAL GAIN vs. FREQUENCY



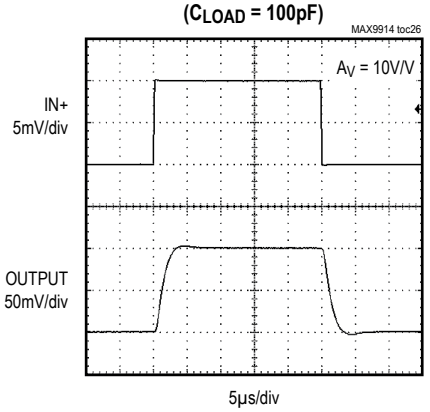
LARGE-SIGNAL GAIN vs. FREQUENCY



SMALL-SIGNAL PULSE RESPONSE (C_{LOAD} = 15pF)



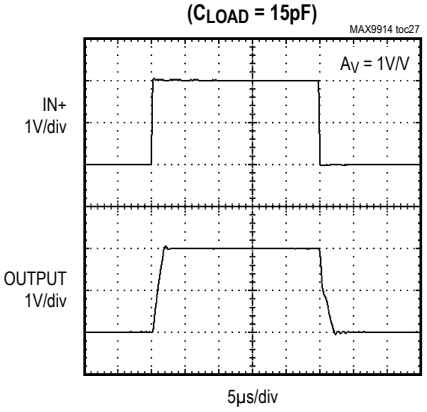
SMALL-SIGNAL PULSE RESPONSE (C_{LOAD} = 100pF)



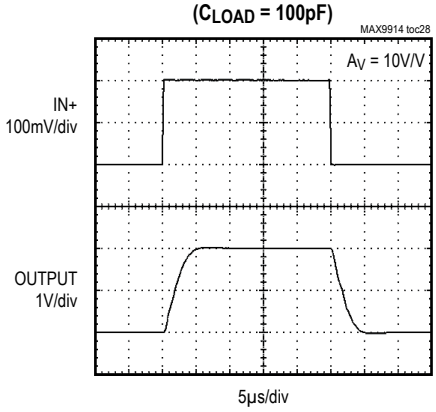
Typical Operating Characteristics (continued)

(V_{DD} = 3V, V_{SS} = V_{CM} = 0V, R_L to V_{DD}/2, T_A = +25°C, unless otherwise noted.)

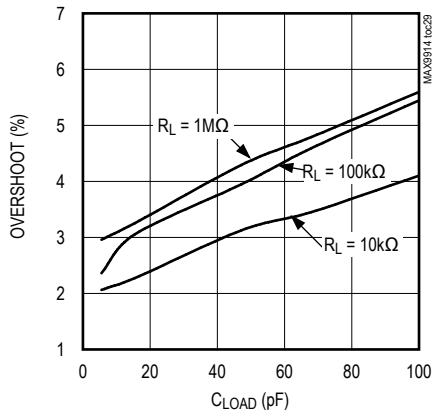
LARGE-SIGNAL PULSE RESPONSE (C_{LOAD} = 15pF)



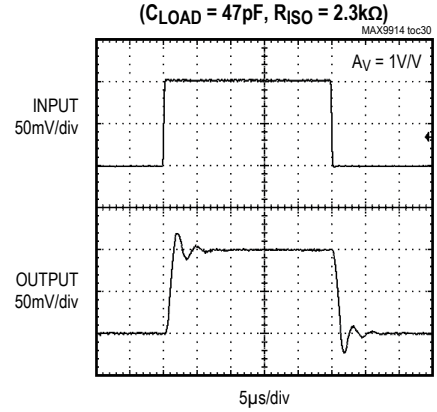
LARGE-SIGNAL PULSE RESPONSE (C_{LOAD} = 100pF)



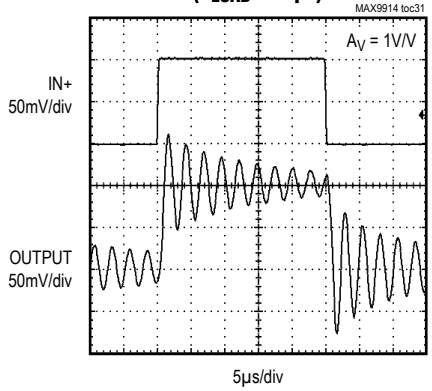
PERCENT OVERSHOOT vs. CAPACITIVE LOAD



OUTPUT WAVEFORM WITH R_{ISO} (C_{LOAD} = 47pF, R_{ISO} = 2.3kΩ)



OUTPUT WAVEFORM WITHOUT R_{ISO} (C_{LOAD} = 47pF)



Pin Description

PIN				NAME	FUNCTION
MAX9914	MAX9915	MAX9916	MAX9917		
1	1	—	—	IN+	Noninverting Amplifier Input
2	2	4	4	V_{SS}	Negative Supply Voltage
3	3	—	—	IN-	Inverting Amplifier Input
4	4	—	—	OUT	Amplifier Output
5	6	8	10	V_{DD}	Positive Supply Voltage
—	5	—	—	$\overline{SHDN}$	Shutdown
—	—	1	1	OUTA	Amplifier Output Channel A
—	—	2	2	INA-	Inverting Amplifier Input Channel A
—	—	3	3	INA+	Noninverting Amplifier Input Channel A
—	—	—	5	$\overline{SHDNA}$	Shutdown Channel A
—	—	—	6	$\overline{SHDNB}$	Shutdown Channel B
—	—	5	7	INB+	Noninverting Amplifier Input Channel B
—	—	6	8	INB-	Inverting Amplifier Input Channel B
—	—	7	9	OUTB	Amplifier Output Channel B

Detailed Description

Featuring a maximized ratio of gain bandwidth to supply current, low operating supply voltage, low input bias current, and rail-to-rail inputs and outputs, the MAX9914–MAX9917 are an excellent choice for precision or general-purpose low-current, low-voltage, battery-powered applications. These CMOS devices consume an ultra-low 20µA (typ) supply current and a 200µV (typ) offset voltage. For additional power conservation, the MAX9914/MAX9917 feature a lowpower shutdown mode that reduces supply current to 1nA (typ), and puts the amplifiers' output in a highimpedance state. These devices are unity-gain stable with a 1MHz gain-bandwidth product driving capacitive loads up to 30pF. The capacitive load can be increased to 100pF when the amplifier is configured for a 10V/V gain.

Rail-to-Rail Inputs and Outputs

The MAX9914–MAX9917 amplifiers all have a parallel-connected n- and p-channel differential input stage that allows an input common-mode voltage range that extends 100mV beyond the positive and negative supply rails, with excellent common-mode rejection.

The MAX9914–MAX9917 are capable of driving the output to within 5mV of both supply rails with a 100kΩ load. These devices can drive a 5kΩ load with swings to within 60mV of the rails. Figure 1 shows no clipping at the output voltage swing of the MAX9914–MAX9917 configured as a unity-gain buffer powered from a single 3V supply.

Low Input Bias Current

The MAX9914–MAX9917 feature ultra-low 1pA (typ) input bias current. The variation in the input bias current is minimal with changes in the input voltage due to very high input impedance (in the order of 1GΩ).

Applications Information

Driving Capacitive Loads

The MAX9914–MAX9917 amplifiers are unity-gain stable for loads up to 30pF. However, the capacitive load can be increased to 100pF when the amplifier is configured for a minimum gain of 10V/V.

Applications that require greater capacitive drive capability should use an isolation resistor between the output and the capacitive load (Figure 2). Also, in unity-gain applications with relatively small R_L (about 5kΩ), the capacitive load can be increased up to 100pF.

Power-Supply Considerations

The MAX9914–MAX9917 are optimized for single 1.8V to 5.5V supply operation. A high amplifier power-supply rejection ratio of 85dB (typ) allows the devices to be powered directly from a battery, simplifying design and extending battery life.

Power-Up Settling Time

The MAX9914–MAX9917 typically require 2µs after power-up. Supply settling time depends on the supply voltage, the value of the bypass capacitor, the output impedance of the incoming supply, and any lead resistance or inductance between components. Op amp settling time depends primarily on the output voltage and is slew-rate limited. Figure 3 shows the MAX991_ in a noninverting voltage follower configuration with the input held at mid-supply. The output settles in approximately 3.5µs for V_{DD} = 3V (see the *Typical Operating Characteristics* for the Power-Up Settling Time graph).

Shutdown Mode

The MAX9915 and MAX9917 feature active-low shutdown inputs. The MAX9915 and MAX9917 enter shutdown in 2µs (typ) and exit shutdown in 10µs (typ). The amplifiers' outputs are high impedance in shutdown mode. Drive $\overline{SHDN}$ low to enter shutdown. Drive $\overline{SHDN}$ high to enable the amplifier. The MAX9917 dual amplifier features separate shutdown inputs. Shut down both amplifiers for lowest quiescent current.

Power-Supply Bypassing and Layout

Bypass V_{DD} with a 0.1µF capacitor to ground as close to the pin as possible to minimize noise.

Good layout techniques optimize performance by decreasing the amount of stray capacitance and inductance to the op amp's inputs and outputs. Minimize stray capacitance and inductance, by placing external components close to the IC.

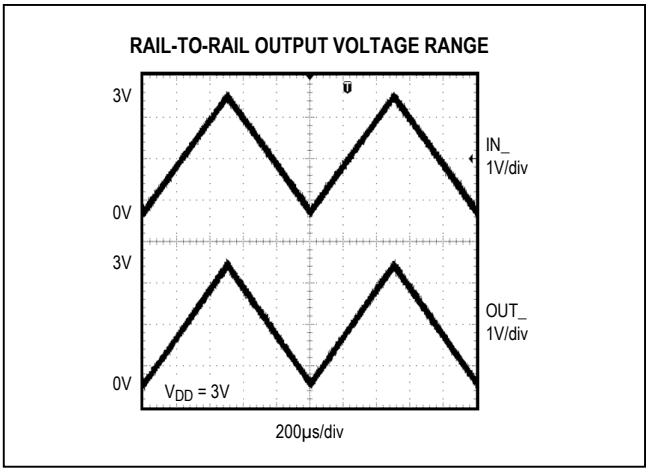


Figure 1. Rail-to-Rail Output Voltage Range

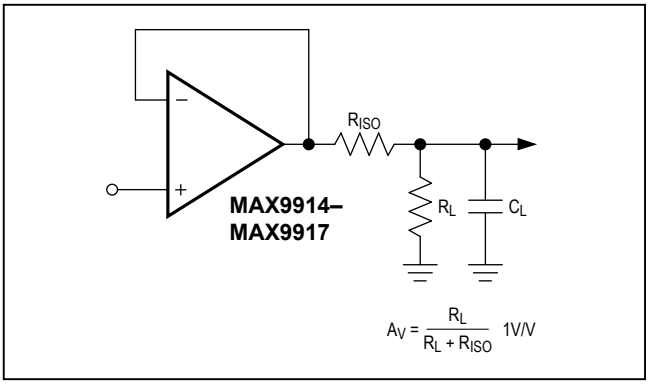


Figure 2. Using a Resistor to Isolate a Capacitive Load from the Op Amp

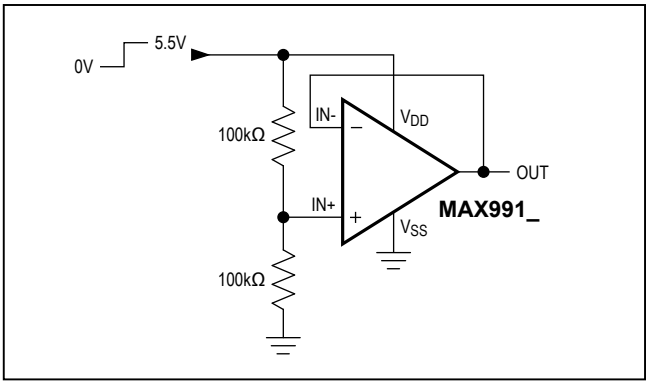
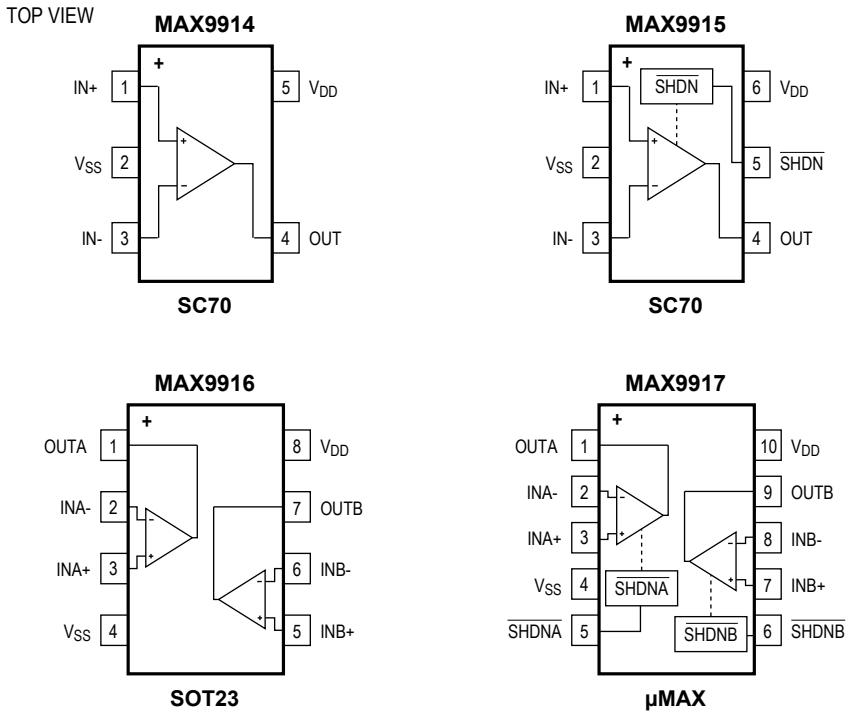


Figure 3. Power-Up Test Configuration

Pin Configurations



Chip Information

PROCESS: BiCMOS

Package Information

For the latest package outline information and land patterns (footprints), go to **www.maximintegrated.com/packages**. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
5 SC70	X5+1	21-0076	90-0188
6 SC70	X6SN+1	21-0077	90-0189
8 SOT23	K8+5	21-0078	90-0176
10 µMAX	U10+2	21-0061	90-0330

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	11/04	Initial release	—
1	10/05	Removed future product asterisks from MAX9916/MAX9917, edited V_{OL}/V_{OH} specifications in the EC table, removed MAX9916 8-pin µMAX package.	1, 2, 11
2	6/13	Updated *Electrical Characteristics*	3, 4
3	11/14	Updated *Absolute Maximum Ratings* and *Electrical Characteristics*	2, 3, 4

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